

FQB27P06TM

Data Sheet

60V P-Channel QFET; Package: TO-263(D2PAK); No of Pins: 2; Container: Tape & Reel,MOSFET 60V P-Channel QFET

Manufacturers	ON Semiconductor, LLC	
Package/Case	TO-263	See.
Product Type	Transistors	
RoHS	Rohs	
Lifecycle		Images are for reference only
Please submit RFQ for FQB27P06TM or <u>Email to us: sales@ovaga.com</u> We will contact you in 12 hours.		

General Description

This P-Channel enhancement mode power MOSFET is produced using a proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

175°C maximum junction temperature rating

Related Products



<u>FQT7N10LTF</u> ON Semiconductor, LLC

ON Semiconductor, LLC SOT-223

FQD19N10LTM

ON Semiconductor, LLC TO-252





FQPF13N50CF

ONSEMI

ON Semiconductor, LLC TO-220F

Application

FQD12N20LTM

ON Semiconductor, LLC TO-252



FQA140N10

ON Semiconductor, LLC TO-3P



FQPF70N10

ON Semiconductor, LLC TO-220F



<u>FQP17P10</u>

ON Semiconductor, LLC TO-220



FQB5N90TM

ON Semiconductor, LLC TO-263